

Description

This is 40V 22A N-channel mosfet in a SOP-8L plastic package.

Uses 2nd generation power trench mosfet technology that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance. This device is well suited for high efficiency fast switching application.

Applications

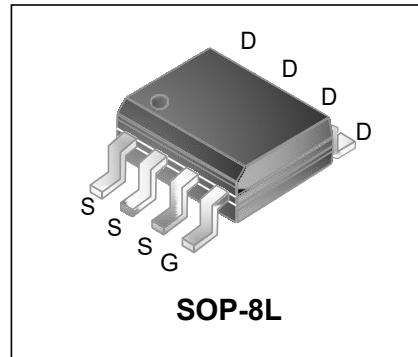
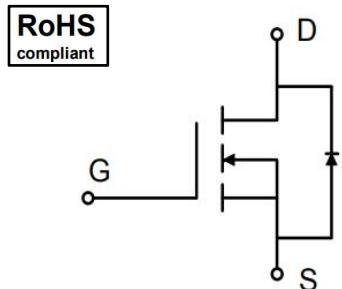
- Power management switches
- DC/DC converter

Features

- Green device available
- Low gate charge
- 100% EAS guaranteed

V_{DSS}	$R_{DS(on)}$	I_D
40 V	3.2 mΩ	22 A

Equivalent Circuit & Pinning



Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	40	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current@10V ¹	I _D	22	A
T _A =75°C		18	
Pulsed Drain Current ²	I _{DM}	165	A
Single Pulse Avalanche Energy ³	E _{AS}	151	mJ
Avalanche Current	I _{AS}	55	A
Total Power Dissipation ⁴	P _D	22	W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance from Junction-to-Ambient ¹	R _{θJA}	76	°C/W
Thermal Resistance from Junction-to-Case ¹	R _{θJC}	41	°C/W

Electrical Characteristics(Ta=25°C)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	40	-	-	V
Gate-Body Leakage current	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$	-	-	± 100	nA
Zero Gate Voltage Drain Current $T_J=25^\circ C$	I_{DSS}	$V_{DS} = 40V, V_{GS} = 0V$	-	-	1	μA
			-	-	5	
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	1.2	1.85	2.2	V
Drain-Source on-Resistance ²	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 15A$	-	2.6	3.2	$m\Omega$
		$V_{GS} = 4.5V, I_D = 10A$	-	3.7	5.2	
Forward Transconductance ²	g_{fs}	$V_{DS} = 5V I_D = 20A$	-	76	-	S
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS} = 20V, V_{GS}=0V, f = 1MHz$	-	2700	-	pF
Output Capacitance	C_{oss}		-	1050	-	
Reverse Transfer Capacitance	C_{rss}		-	45	-	
Switching Characteristics						
Gate Resistance	R_g	$V_{DS} = 0V, V_{GS}=0V, f = 1MHz$	-	0.7	-	Ω
Total Gate Charge	Q_g	$V_{GS} = 4.5V, V_{DS} = 20V, I_D = 20A$	-	22.5	-	nC
Gate-Source Charge	Q_{gs}		-	7.6	-	
Gate-Drain Charge	Q_{gd}		-	5.4	-	
Turn-on Delay Time	$t_{d(on)}$	$V_{GS}=10V, V_{DS} = 20V, R_G = 3\Omega, I_D = 20A$	-	9.8	-	nS
Rise Time	t_r		-	5.2	-	
Turn-off Delay Time	$t_{d(off)}$		-	32	-	
Fall Time	t_f		-	6.6	-	
Drain-Source Body Diode Characteristics						
Diode Forward Voltage ²	V_{SD}	$I_S = 1A, V_{GS} = 0V$	-	-	1	V
Continuous Source Current ^{1,5}	I_S	$V_G=V_D=0V, \text{Force Current}$	-	-	22	A

Notes:

- 1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
3. The EAS data shows Max. rating . The test condition is $V_{DD}=25V, V_{GS}=10V, L=0.1mH, I_{AS}=55A$
- 4.The power dissipation is limited by $150^\circ C$ junction temperature
5. The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation

Electrical Characteristic Curve

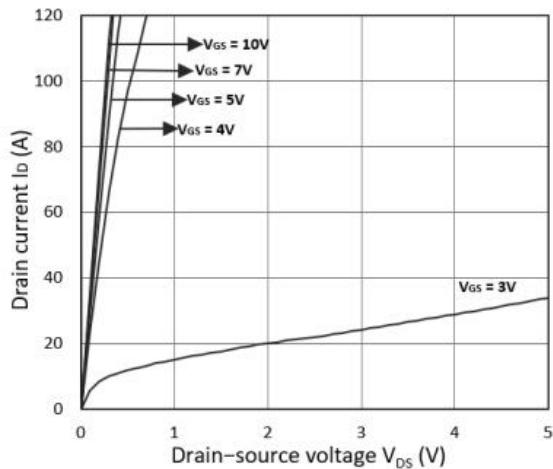


Figure 1. Output Characteristics

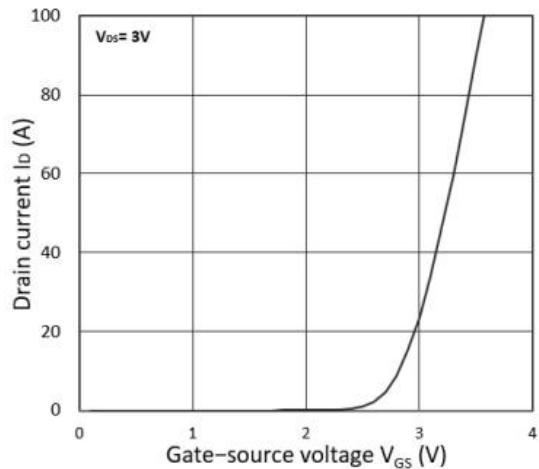


Figure 2. Transfer Characteristics

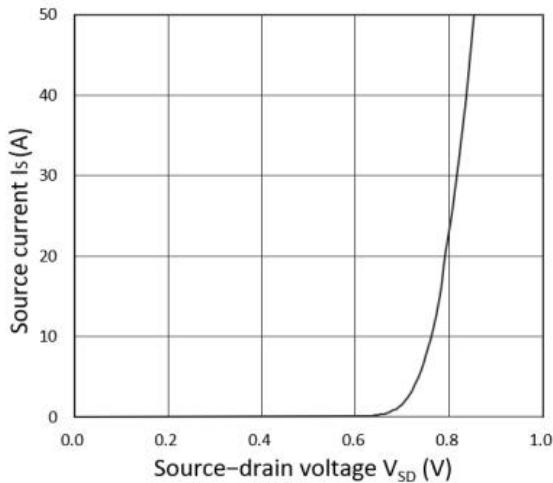


Figure 3. Forward Characteristics of Reverse

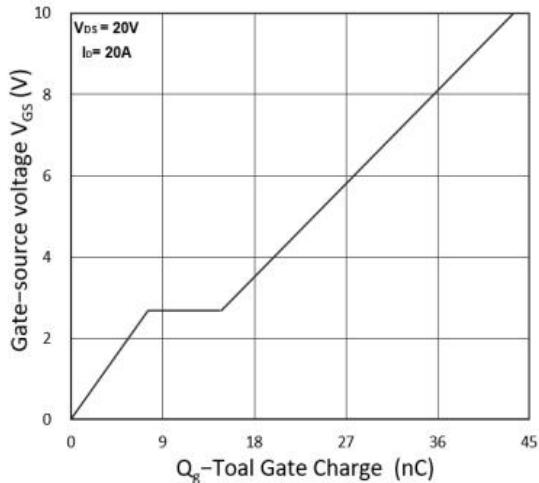


Figure 4. Gate Charge Characteristics

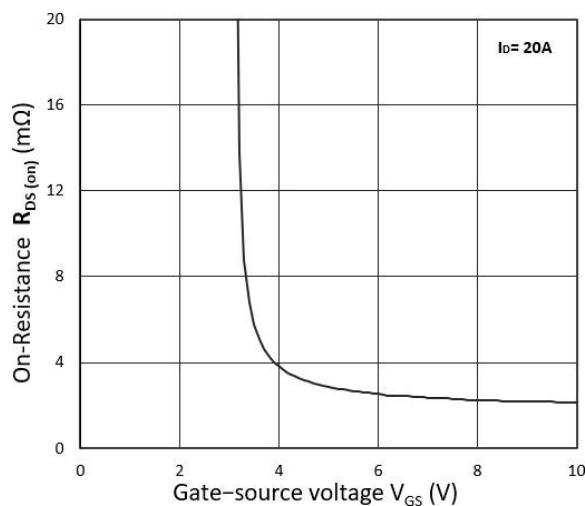


Figure 5. $R_{DS(on)}$ vs. V_{GS}

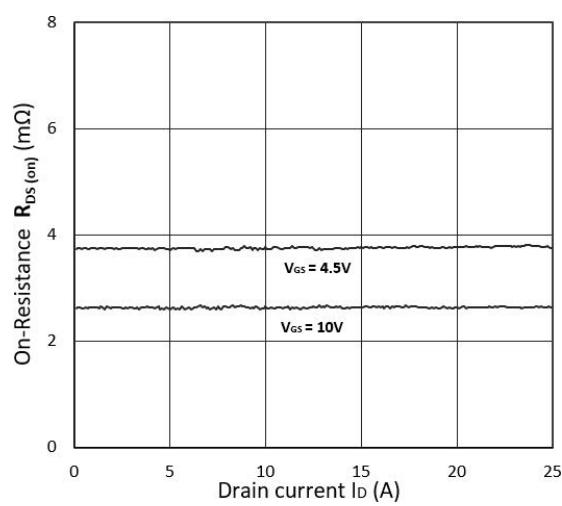


Figure 6. $R_{DS(on)}$ vs. I_D

Electrical Characteristic Curve

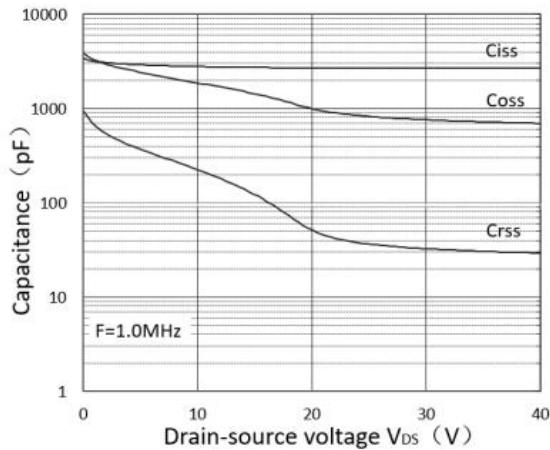


Figure 7. Capacitance Characteristics

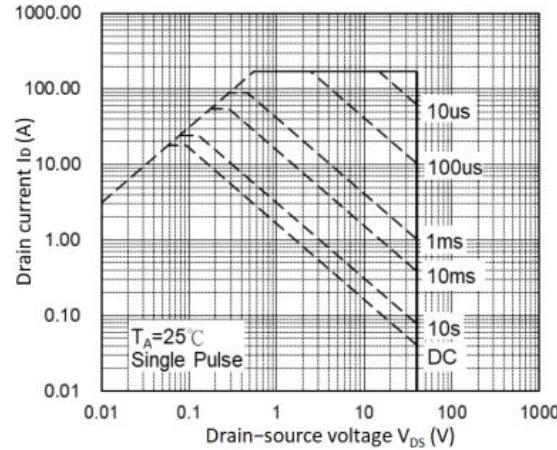


Figure 8. Safe Operating Area

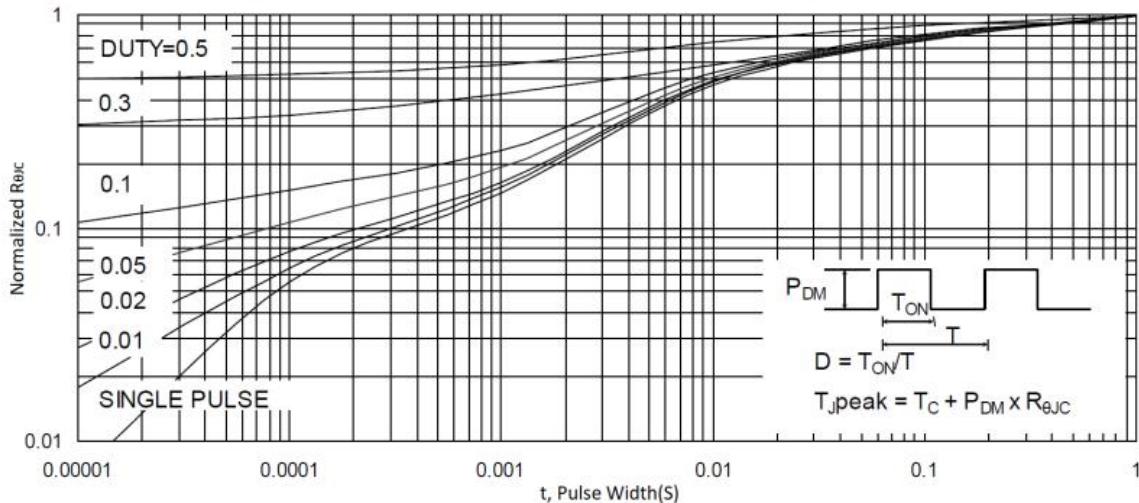


Figure 9. Normalized Maximum Transient Thermal Impedance

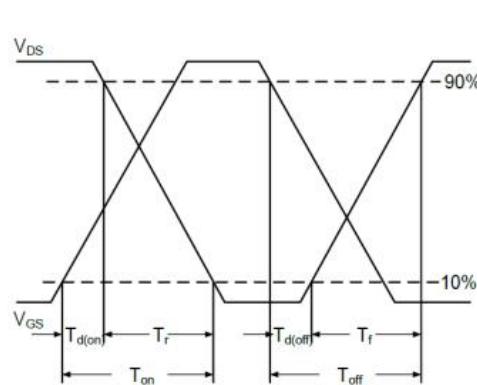


Figure 10. Switching Time Waveform

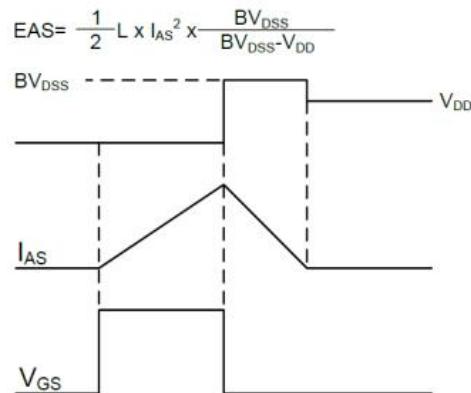
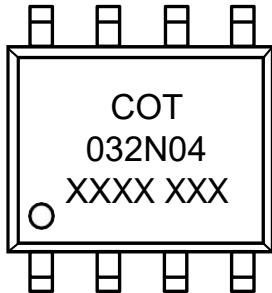


Figure 11. Unclamped Inductive Switching

Waveform

Marking Instructions



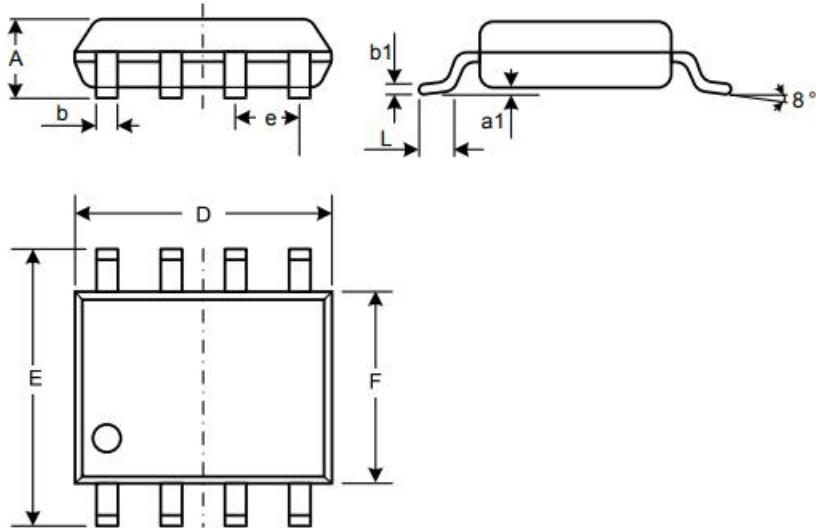
Note:

- COT: Company Logo
032N04: Product Type
XXXX XXX: Date code

Ordering Information

Part	Package	Marking	Packing method
CT032N04SC	SOP-8L	032N04	Tape and Reel

Mechanical Dimensions for SOP-8L



COMMON DIMENSIONS

SYMBOL	MM	
	MIN	MAX
A	1.23	1.75
a1	0.05	0.25
b	0.31	0.51
b1	0.16	0.25
D	4.70	5.15
E	5.75	6.25
e	1.07	1.47
F	3.70	4.10
L	0.4	1.27